



PATENT ATTORNEY DOCKET NO. 46884-5461

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Kenshi FUKUMITSU et al.) Confirmation No.: 3680
U.S. Application No.: 10/571,142) Group Art Unit: 2811
Filed: March 9, 2006) Examiner: Unassigned
For: SEMICONDUCTOR SUBSTRATE CUTTING METHOD))
Commissioner for Patents U.S. Patent and Trademark Office Customer Window Mail Stop: New Application Alexandria, VA 22314	⊠ Amendment □ AF □ Issue Fee
Sir: <u>INFORMATION DISCLOS</u> I	URE STATEMENT (IDS)
Under 37 C.F.R. § 1.97(b): Pursuant to 3 brings to the attention of the Examiner the docume the undersigned's knowledge, this IDS is being file Action on the merits, before the mailing date of a f RCE under § 1.114, or within three months of the a	ents listed on the attached PTO Form 1449. To ed before the mailing date of a first Office first Office Action on the merits after filing an
Under 37 C.F.R. § 1.97(c): Pursuant to 37 to the attention of the Examiner the documents listed is being filed after the events recited in § 1.97(b) by mailing date of a Final Office Action, a Notice of Approsecution in the application.	ut, to the undersigned's knowledge, before the
The fee of \$180.00 set forth in § 1.1	7(p) is included herein; or
	information contained in this IDS was first foreign patent office in a counterpart foreign of this IDS.
Under 37 C.F.R. § 1.97(d): Pursuant to 3 brings to the attention of the Examiner the docume This IDS is being filed after the events recited in §	ents listed on the attached PTO Form 1449.
The fee of \$180.00 set forth in § 1.1	7(p) is included herein; and
Applicant submits that each item of cited in any communication from a application not more than three more	information contained in this IDS was first foreign patent office in a counterpart foreign of this IDS.

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Page 3

Under 37 C.F.R. § 1.97(i): Pursuant to 37 C.F.R. §§ 1.56 and 1.97(i), Applicant brings
to the attention of the Examiner the documents listed on the attached PTO Form 1449. This IDS
is being filed after the events recited in § 1.97(d). Applicant requests that the IDS be placed in
the file.
A search report or other listing of documents from a counterpart, related, or other
application dated and having documents cited thereon is attached for the
Examiner's consideration. Any of these documents not previously cited, and any additional
documents are listed on the PTO Form 1449.
Applicant respectfully requests that the Examiner consider the listed documents and
evidence that consideration by making appropriate notations on the attached form. As for any
document listed on the accompanying PTO-1449 that is in a language other than English,
relevance can be understood from an enclosed English abstract or at least partial translation or
from mention in the specification or in a search report for a corresponding application.
This submission does not represent that a search has been made or that no better art exists and
does not constitute an admission that any of the listed documents are material or constitute "prior art." If
it should be determined that any of the listed documents do not constitute "prior art" under United States
law, Applicant reserve the right to present to the Office the relevant facts and law regarding the
appropriate status of such documents.
Applicant further reserves the right to take appropriate action to establish the patentability of the
disclosed invention over the listed documents, should any of the documents be applied against the claims
of the present application.
Except for issue fees payable under 37 C.F.R. § 1.18, the Commissioner is hereby authorized by
this paper to charge any additional fees during the entire pendency of this Application, including fees due
under 37 C.F.R. § 1.16 and 1.17 which may be required and including any required extension of time

fees, or credit any overpayment to Deposit Account No. 50-0573. This paragraph is intended to be a CONSTRUCTIVE PETITION FOR EXTENSION OF TIME in accordance with 37 C.F.R. § 1.136(a)(3).

Respectfully submitted,

DRINKER, BIDDLE & REATH LLP

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Dated: July 31, 2007

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Attorney Docket No.:

Serial No.:

10/571,142

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Applicants

Kenshi FUKUMITSU et al.

PTO Form 1449

Filing Date:
March 9, 2006

Attorney Docket No.:

Serial No.:

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Group Art Unit:
2811

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Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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